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Electronic and Optical Properties of monolayer MX₂ M= Zr, Hf; X= S, Se from first principles calculations

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Abstract content
 (Max 300 words)
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Transition metal di-chalcogenide (TMDC) monolayer have potential applications in electronic and optical devices. Work on these atomically thin semiconductors is an exciting emerging field of research. In this research the electronic, photo-emission and photo-absorption properties of monolayer ZrS₂, ZrSe₂, HfS₂ and HfSe₂ have been investigated using density functional theory (DFT) and many body perturbation theory at the level of the partially self consistent GW₀ approximation. Solution of the Bethe-Salpeter equation (BSE) in the Tamm-Dancoff approximation was used to investigate the optical properties of these monolayer TMDCs. The structures were found to be semiconductor with band gaps within the visible range of the spectrum. Exciton binding energies were estimated from a comparison of the GW and BSE results.

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Yes

Level for award (Hons, MSc, PhD, N/A)?

PhD

Main supervisor (name and email) and his / her institution

Daniel.Joubert2@wits.ac.za

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Primary author: Mr ABDULSALAM, Mahmud (Wits University)

Co-authors: Prof. JOUBERT, Daniel (Wits University); Mr DONGHO NGUIMDO, Guy Moise (Wits University)

Presenter: Mr ABDULSALAM, Mahmud (Wits University)

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